ON Semiconductor

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Complementary Darlington Power Transistors

DPAK For Surface Mount Applications

Designed for general purpose power and switching such as output or driver stages in applications such as switching regulators, converters, and power amplifiers.

Features

- Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("-1" Suffix)
- Electrically Similar to Popular TIP31 and TIP32 Series
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant*



ON Semiconductor®

http://onsemi.com

SILICON POWER TRANSISTORS 2 AMPERES 100 VOLTS, 20 WATTS





DPAK CASE 369C

DPAK-3 CASE 369D

MARKING DIAGRAMS





A = Assembly Location

Y = Year WW = Work Week x = 2 or 7

G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V _{CEO}	100	Vdc
Collector-Base Voltage	V _{CB}	100	Vdc
Emitter-Base Voltage	V _{EB}	5	Vdc
Collector Current Continuous Peak	I _C	2 4	Adc
Base Current	Ι _Β	50	mAdc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	20 0.16	W W/°C
Total Power Dissipation (Note1) @ T _A = 25°C Derate above 25°C	P _D	1.75 0.014	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	6.25	°C/W
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	71.4	°C/W

^{1.} These ratings are applicable when surface mounted on the minimum pad sizes recommended.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage (Note 2) $(I_C = 30 \text{ mAdc}, I_B = 0)$	V _{CEO(sus)}	100	-	Vdc
Collector Cutoff Current (V _{CE} = 50 Vdc, I _B = 0)	I _{CEO}	-	20	μAdc
Collector Cutoff Current (V _{CB} = 100 Vdc, I _E = 0)	I _{CBO}	-	20	μAdc
Emitter Cutoff Current (V _{BE} = 5 Vdc, I _C = 0)	I _{EBO}	-	2	mAdc
Collector-Cutoff Current (V _{CB} = 80 Vdc, I _E = 0)	I _{CBO}	_	10	μAdc
Emitter-Cutoff Current (V _{BE} = 5 Vdc, I _C = 0)	I _{EBO}	-	2	mAdc
ON CHARACTERISTICS				•
DC Current Gain	h _{FE}	500 1000 200	12,000 -	-
Collector–Emitter Saturation Voltage ($I_C = 2$ Adc, $I_B = 8$ mAdc) ($I_C = 4$ Adc, $I_B = 40$ mAdc)	V _{CE(sat)}	- -	2 3	Vdc
Base-Emitter Saturation Voltage (I _C = 4 Adc, I _B = 40 mAdc)	V _{BE(sat)}	_	4	Vdc
Base-Emitter On Voltage (I _C = 2 Adc, V _{CE} = 3 Vdc)	V _{BE(on)}	-	2.8	Vdc
DYNAMIC CHARACTERISTICS				
Current-Gain - Bandwidth Product ($I_C = 0.75$ Adc, $V_{CE} = 10$ Vdc, $f = 1$ MHz)	f⊤	25	-	MHz
Output Capacitance $ \begin{array}{l} (V_{CB}=10\ \text{Vdc},\ I_E=0,\ f=0.1\ \text{Mhz})\\ \text{MJD117},\ \text{NJVMJD117T4G}\\ \text{MJD112},\ \text{NJVMJD112G},\ \text{NJVMJD112T4G} \end{array} $	C _{ob}	- -	200 100	pF

^{2.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%. *These ratings are applicable when surface mounted on the minimum pad sizes recommended.

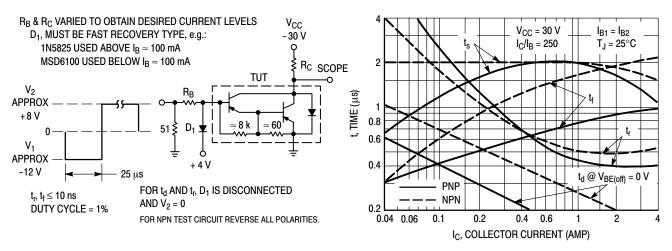


Figure 1. Switching Times Test Circuit

Figure 2. Switching Times

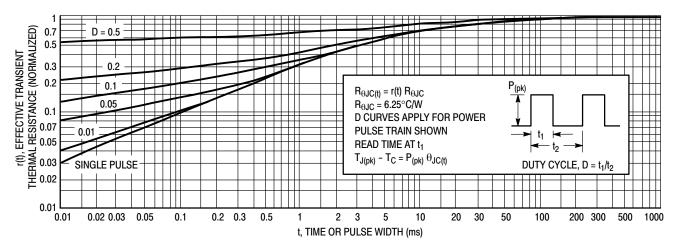


Figure 3. Thermal Response

ACTIVE-REGION SAFE-OPERATING AREA

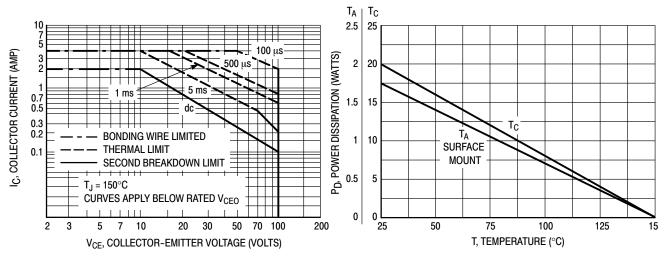
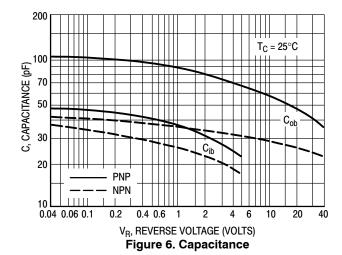


Figure 4. Maximum Rated Forward Biased Safe Operating Area

Figure 5. Power Derating

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figures 5 and 6 is based on $T_{J(pk)}$ = 150°C; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)}$ < 150°C. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.



TYPICAL ELECTRICAL CHARACTERISTICS

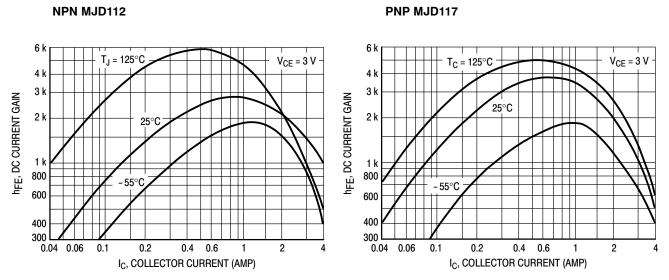


Figure 7. DC Current Gain

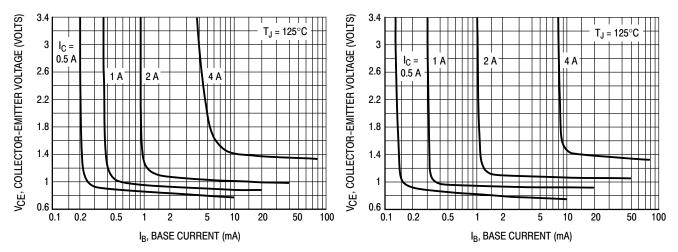


Figure 8. Collector Saturation Region

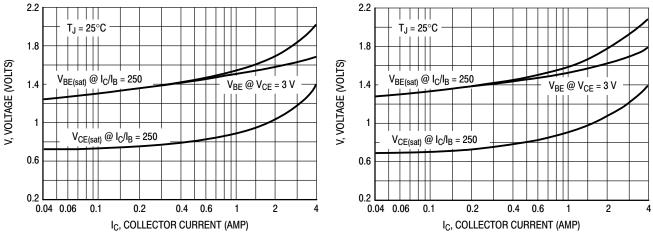


Figure 9. "On Voltages

NPN MJD112 PNP MJD117

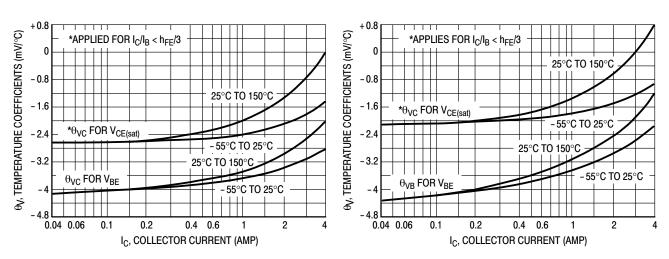


Figure 10. Temperature Coefficients

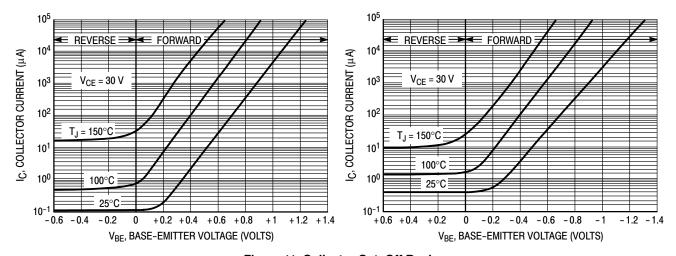


Figure 11. Collector Cut-Off Region

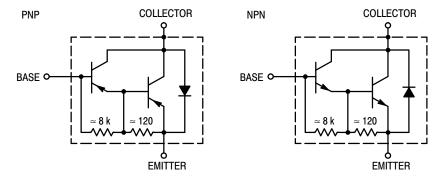


Figure 12. Darlington Schematic

ORDERING INFORMATION

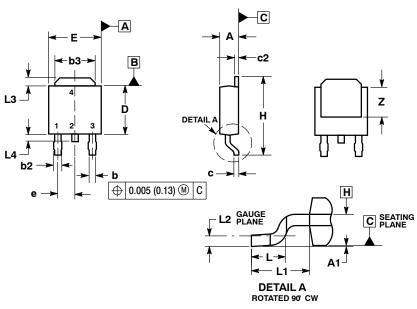
Device	Package Type	Package	Shipping [†]	
MJD112G	DPAK (Pb-Free)	369C	75 Units / Rail	
NJVMJD112G*	DPAK (Pb-Free)	369C	75 Units / Rail	
MJD112-1G	DPAK-3 (Pb-Free)	369D	75 Units / Rail	
MJD112RLG	DPAK (Pb-Free)	369C	1,800 Tape & Reel	
MJD112T4G	DPAK (Pb-Free)	369C	2,500 Tape & Reel	
NJVMJD112T4G*	DPAK (Pb-Free)	369C	2,500 Tape & Reel	
MJD117G	DPAK (Pb-Free)	369C	75 Units / Rail	
MJD117-1G	DPAK-3 (Pb-Free)	369D	75 Units / Rail	
MJD117RLG	DPAK (Pb-Free)	369C	1,800 Tape & Reel	
MJD117T4G	DPAK (Pb-Free)	369C	2,500 Tape & Reel	
NJVMJD117T4G*	DPAK (Pb-Free)	369C	2,500 Tape & Reel	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP

Capable.

PACKAGE DIMENSIONS

DPAK CASE 369C ISSUE D



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. CONTROLLING DIMENSION: INCHES.

 3. THERMAL PAD CONTOUR OPTIONAL WITHIN DI-

- MENSIONS b3, L3 and Z.

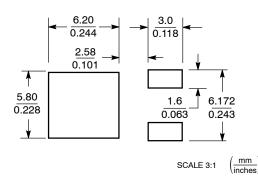
 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL
- NOT EXCEED 0.006 INCHES PER SIDE.

 5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.

 6. DATUS A AND B ARE DETERMINED AT DATUM

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.086	0.094	2.18	2.38	
A1	0.000	0.005	0.00	0.13	
b	0.025	0.035	0.63	0.89	
b2	0.030	0.045	0.76	1.14	
b3	0.180	0.215	4.57	5.46	
С	0.018	0.024	0.46	0.61	
c2	0.018	0.024	0.46	0.61	
D	0.235	0.245	5.97	6.22	
Е	0.250	0.265	6.35	6.73	
е	0.090 BSC		2.29 BSC		
Н	0.370	0.410	9.40	10.41	
L	0.055	0.070	1.40	1.78	
L1	0.108 REF		2.74	REF	
L2	0.020 BSC		0.51	BSC	
L3	0.035	0.050	0.89	1.27	
L4		0.040	-	1.01	
Z	0.155		3.93		

SOLDERING FOOTPRINT*



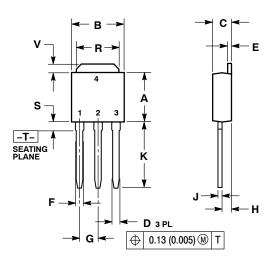
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

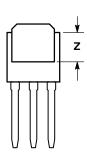
STYLE 1:

- PIN 1. BASE
 2. COLLECTOR
 3. EMITTER
 4. COLLECTOR

PACKAGE DIMENSIONS

IPAK CASE 369D ISSUE C





NOTES

- DIMENSIONING AND TOLERANCING PER
 ANSI Y14.5M. 1982.
- 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.245	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090 BSC		2.29 BSC	
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
٧	0.035	0.050	0.89	1.27
Z	0.155		3.93	

STYLE 1:

PIN 1. BASE

- 2. COLLECTOR
- 3. EMITTER 4. COLLECTOR

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